imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

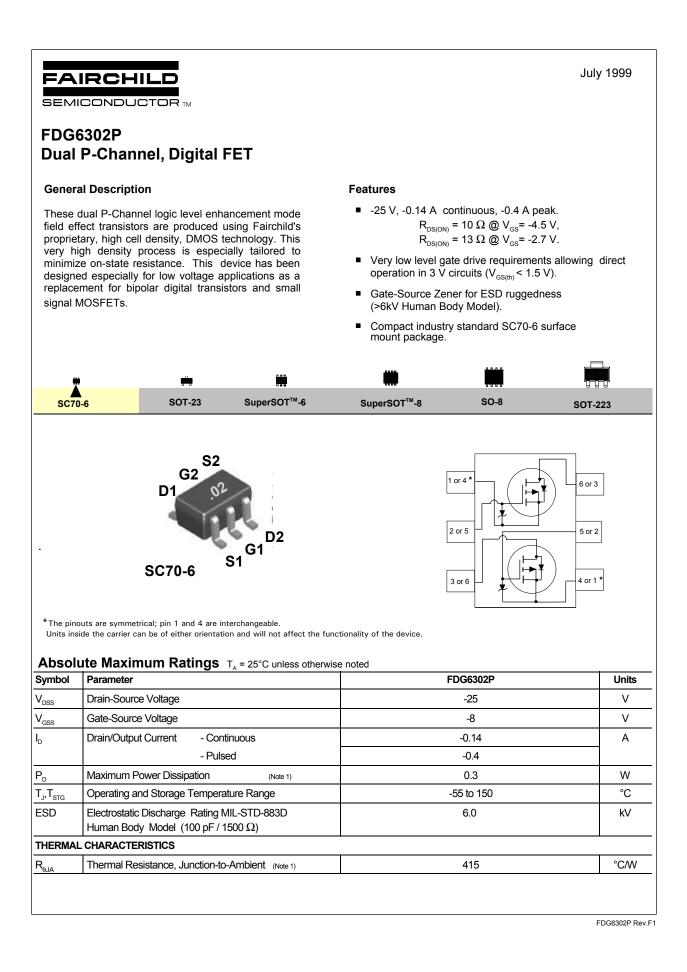
We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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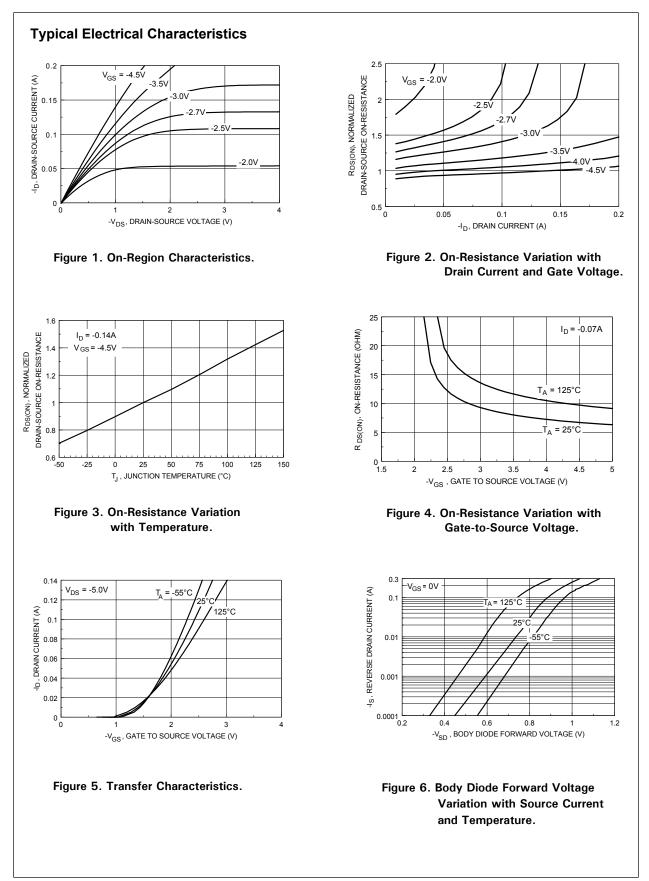


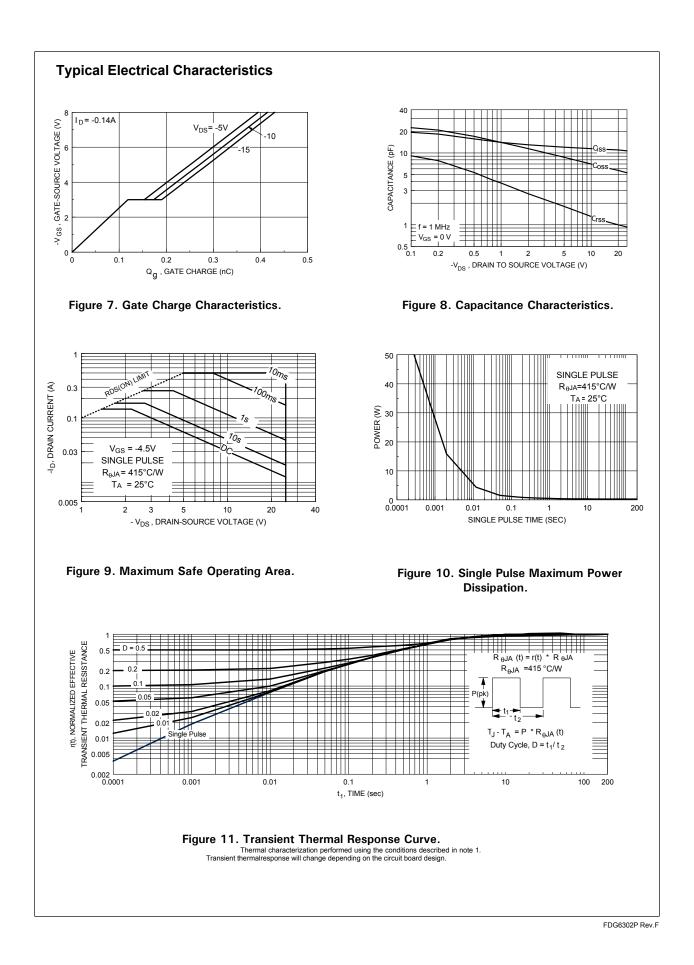


| Symbol | Parameter | Conditions | Min | Тур | Max | Units |
|----------------------------------|---|---|-------|------|-------|---------|
| OFF CHAR | ACTERISTICS | | | | | • |
| BV _{DSS} | Drain-Source Breakdown Voltage | $V_{GS} = 0 V, I_{D} = -250 \mu A$ | -25 | | | V |
| $\Delta BV_{DSS}/\Delta T_{J}$ | Breakdown Voltage Temp. Coefficient | I_{D} = -250 µA, Referenced to 25°C | | -19 | | mV /°C |
| I _{DSS} | Zero Gate Voltage Drain Current | $V_{\rm DS} = -20 \text{V}, V_{\rm GS} = 0 \text{V}$ | | | -1 | μA |
| | | T _J = 55°C | | | -10 | μA |
| I _{GSS} | Gate - Body Leakage Current | $V_{GS} = -8 V, V_{DS} = 0 V$ | | | -100 | nA |
| ON CHARAC | CTERISTICS (Note 2) | | 11 | | | |
| V _{GS(th)} | Gate Threshold Voltage | $V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$ | -0.65 | -0.9 | -1.5 | V |
| $\Delta V_{GS(th)} / \Delta T_J$ | Gate Threshold Voltage Temp.Coefficient | I_{D} = -250 µA, Referenced to 25°C | | 2 | | mV / °C |
| R _{DS(ON)} | Static Drain-Source On-Resistance | V _{GS} = -4.5 V, I _D = -0.14 A | | 7.3 | 10 | Ω |
| | | T _J =125°C | | 11 | 17 | |
| | | V _{GS} = -2.7 V, I _D = -0.05 A | | 10.4 | 13 | |
| I _{D(ON)} | On-State Drain Current | $V_{GS} = -4.5 V, V_{DS} = -5 V$ | -0.14 | | | А |
| 9 _{FS} | Forward Transconductance | $V_{\rm DS} = -5 V, I_{\rm D} = -0.14 A$ | | 0.12 | | S |
| DYNAMIC C | HARACTERISTICS | | | | | |
| C _{iss} | Input Capacitance | $V_{DS} = -10 V, V_{GS} = 0 V,$ f = 1.0 MHz | | 12 | | pF |
| C _{oss} | Output Capacitance | f = 1.0 MHz | | 7 | | pF |
| C _{rss} | Reverse Transfer Capacitance | | | 1.5 | | pF |
| SWITCHING | CHARACTERISTICS (Note 2) | | | | | |
| t _{D(on)} | Turn - On Delay Time | $V_{DD} = -5 V, I_{D} = -0.25 A,$ | | 5 | 12 | ns |
| ţ | Turn - On Rise Time | V_{GS} = -4.5 V, R_{GEN} = 6 Ω | | 8 | 16 | ns |
| t _{D(off)} | Turn - Off Delay Time | | | 9 | 18 | ns |
| t _r | Turn - Off Fall Time | | | 5 | 10 | ns |
| Q _g | Total Gate Charge | $V_{DS} = -5 V, I_{D} = -0.14 A,$ $V_{GS} = -4.5 V$ | | 0.22 | 0.31 | nC |
| Q _{gs} | Gate-Source Charge | $v_{GS} = -4.5 V$ | | 0.12 | | nC |
| Q_{gd} | Gate-Drain Charge | | | 0.05 | | nC |
| DRAIN-SOU | RCE DIODE CHARACTERISTICS AND MAXIMI | UM RATINGS | 1 | | | |
| l _s | Maximum Continuous Source Current | | | | -0.25 | Α |
| V _{SD} | Drain-Source Diode Forward Voltage | $V_{GS} = 0 V, I_{S} = -0.25 A (Note 2)$ | | -0.8 | -1.2 | V |

Notes:

1. R_{pk} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{pkc} is guaranteed by design while R_{hcA} is determined by the user's board design. $R_{hbA} = 415^{\circ}$ C/W on minimum pad mounting on FR-4 board in still air. 2. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2.0%.





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